











SNVS008L-SEPTEMBER 1998-REVISED JUNE 2016

LM2671

# LM2671 SIMPLE SWITCHER® Power Converter High Efficiency 500-mA **Step-Down Voltage Regulator With Features**

#### **Features**

- Efficiency up to 96%
- Available in 8-Pin SOIC, PDIP, and WSON **Packages**
- Simple and Easy to Design With
- Requires Only 5 External Components
- Uses Readily Available Standard Inductors
- 3.3-V, 5-V, 12-V, and Adjustable Output Versions
- Adjustable Version Output Voltage Range: 1.21 V to 37 V
- ±1.5% Maximum Output Voltage Tolerance Over Line and Load Conditions
- Ensured 500-mA Output Load Current
- 0.25-Ω DMOS Output Switch
- Wide Input Voltage Range: 8 V to 40 V
- 260-kHz Fixed Frequency Internal Oscillator
- TTL Shutdown Capability, Low Power Standby Mode
- Soft-Start and Frequency Synchronization
- Thermal Shutdown and Current-Limit Protection

# Applications

- Simple High Efficiency (> 90%) Step-Down (Buck) Regulators
- Efficient Preregulator for Linear Regulators

# 3 Description

The LM2671 series of regulators are monolithic integrated circuits built with a LMDMOS process. These regulators provide all the active functions for a step-down (buck) switching regulator, capable of driving a 500-mA load current with excellent line and load regulation. These devices are available in fixed output voltages of 3.3 V, 5 V, 12 V, and an adjustable output version.

minimum number Requiring οf external components, these regulators are simple to use and include patented internal frequency compensation, fixed frequency oscillator, external shutdown, soft start, and frequency synchronization.

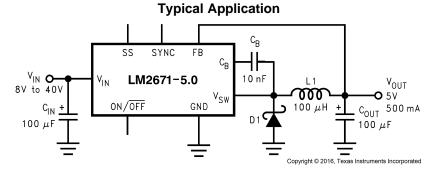
The LM2671 series operates at a switching frequency of 260 kHz, thus allowing smaller sized filter components than what is required with lower frequency switching regulators. Because of its very high efficiency (> 90%), the copper traces on the printed-circuit board are the only heat sinking required.

A family of standard inductors for use with the are available from several manufacturers. This feature greatly simplifies the design of switch-mode power supplies using these advanced ICs. Also included in the data sheet are selector guides for diodes and capacitors designed to work in switch-mode power supplies.

# Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SOIC (8)	4.90 mm × 3.91 mm
LM2674	PDIP (8)	9.81 mm × 6.35 mm
	WSON (16)	5.00 mm × 5.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



For fixed output voltage versions



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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

# Changes from Revision K (April 2013) to Revision L

**Page** 

- Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section
   Removed all references to Computer Design Software LM267X Made Simple (Version 6.0)
- Changes from Revision J (April 2013) to Revision K

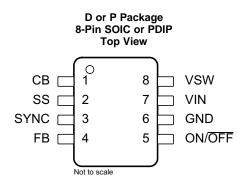
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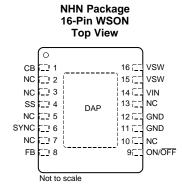


# 5 Description (continued)

Other features include a ensured  $\pm 1.5\%$  tolerance on output voltage within specified input voltages and output load conditions, and  $\pm 10\%$  on the oscillator frequency. External shutdown is included, featuring typically 50- $\mu$ A standby current. The output switch includes current limiting, as well as thermal shutdown for full protection under fault conditions.

# 6 Pin Configuration and Functions





Connect DAP to pin 11 and 12

#### **Pin Functions**

	PIN		1/0	DECORIDATION
NAME	SOIC, PDIP	WSON	I/O	DESCRIPTION
СВ	1	1	I	Bootstrap capacitor connection for high-side driver. Connect a high-quality, 100-nF capacitor from CB to VSW Pin.
SS	2	4	I	Soft-start Pin. Connect a capacitor from this pin to GND to control the output voltage ramp. If the feature not desired, the pin can be left floating.
SYNC	3	6	I	This input allows control of the switching clock frequency. If left open-circuited the regulator is switched at the internal oscillator frequency, typically 260 kHz.
FB	4	8	I	Feedback sense input pin. Connect to the midpoint of feedback divider to set VOUT for ADJ version or connect this pin directly to the output capacitor for a fixed output version.
ON/OFF	5	9	I	Enable input to the voltage regulator. High = ON and low = OFF. Pull this pin high or float to enable the regulator
VSW	8	15, 16	0	Source pin of the internal high-side FET. This is a switching node. Attached this pin to an inductor and the cathode of the external diode.
GND	6	11, 12	_	Power ground pins. Connect to system ground. Ground pins of $C_{\text{IN}}$ and $C_{\text{OUT}}$ . Path to $C_{\text{IN}}$ must be as short as possible.
VIN	7	14	I	Supply input pin to collector pin of high-side FET. Connect to power supply and input bypass capacitors $C_{\text{IN}}$ . Path from VIN pin to high frequency bypass $C_{\text{IN}}$ and GND must be as short as possible.
NC	_	2, 3, 5, 7, 10, 13	_	No connect pins



# 7 Specifications

# 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)(2)

			MIN	MAX	UNIT
Supply voltage				45	V
ON/ <del>OFF</del> pin voltage, V <sub>SH</sub>			-0.1	6	V
Switch voltage to groun	nd			-1	V
Boost pin voltage				V <sub>SW</sub> + 8	V
Feedback pin voltage, V <sub>FB</sub>			-0.3	14	V
Power dissipation			Internall	Internally Limited	
	Dinaskaga	Vapor phase (60 s)		215	
Load tomporature	D package	Infrared (15 s)		220	20
Lead temperature	P package (solder	ng, 10 s)		260	°C
	WSON package		See A	N-1187	
Maximum junction tem	Maximum junction temperature			150	°C
Storage temperature, 7	torage temperature, T <sub>sto</sub>			150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 7.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)(2)	±2000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

# 7.3 Recommended Operating Conditions

	MIN	MAX	UNIT
Supply voltage	6.5	40	٧
Junction temperature, T <sub>J</sub>	-40	125	°C

# 7.4 Thermal Information

		LM2674		
THERMAL METRIC <sup>(1)</sup>	D (SOIC)	P (PDIP)	NHN (WSON)	UNIT
	8 PINS	8 PINS	16 PINS	
R <sub>0JA</sub> Junction-to-ambient thermal resistance (2)	105	95	_	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

<sup>(2)</sup> If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

<sup>(2)</sup> The human body model is a 100-pF capacitor discharged through a 1.5-k $\Omega$  resistor into each pin.

<sup>(2)</sup> Junction to ambient thermal resistance with approximately 1 square inch of printed-circuit board copper surrounding the leads. Additional copper area lowers thermal resistance further. The value R<sub>0JA</sub> for the WSON (NHN) package is specifically dependent on PCB trace area, trace material, and the number of layers and thermal vias. For improved thermal resistance and power dissipation for the WSON package, see *AN-1187 Leadless Leadframe Package (LLP)*.



#### 7.5 Electrical Characteristics – 3.3 V

Specifications are for  $T_1 = 25^{\circ}$ C (unless otherwise noted).

		j = 20 0 (driiees strietwiss ii		(4)	(0)	(4)					
P	PARAMETER	TEST C	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT					
SYSTEM PARAMETERS(3)											
		\/ - 9 \/ to 40 \/	$T_J = 25$ °C	3.251	3.3	3.399					
		$V_{IN} = 8 \text{ V to } 40 \text{ V},$ $I_{LOAD} = 20 \text{ mA to } 500 \text{ mA}$ Over full operating temperature range 3.201		3.399	V						
V <sub>OUT</sub>	Output voltage	V 65 V to 40 V	$T_J = 25^{\circ}C$	3.251	3.3	3.35					
		V <sub>IN</sub> = 6.5 V to 40 V, I <sub>LOAD</sub> = 20 mA to 250 mA	Over full operating temperature range	3.201		3.399	V				
η	Efficiency	V <sub>IN</sub> = 12 V, I <sub>LOAD</sub> = 500 mA		_	86%						

<sup>(1)</sup> All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

(2) Typical numbers are at 25°C and represent the most likely norm.

#### 7.6 Electrical Characteristics – 5 V

Specifications are for  $T_1 = 25^{\circ}C$  (unless otherwise noted).

P	PARAMETER TEST CONDITIONS			MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT				
SYSTEM PARAMETERS(3)											
		\/ - 9 \/ to 40 \/	$T_J = 25$ °C	4.925	5	5.15 5 5.075					
	Output valtage	$V_{IN} = 8 \text{ V to } 40 \text{ V},$ $I_{LOAD} = 20 \text{ mA to } 500 \text{ mA}$ Over full operating temperature range  4.85		5.15	V						
V <sub>OUT</sub>	Output voltage	V 6 5 V to 40 V	$T_J = 25^{\circ}C$	4.925	5	5.075					
		$V_{IN} = 6.5 \text{ V to } 40 \text{ V},$ $I_{LOAD} = 20 \text{ mA to } 250 \text{ mA}$	Over full operating temperature range	4.85		5.15	V				
η	Efficiency	V <sub>IN</sub> = 12 V, I <sub>LOAD</sub> = 500 mA	V <sub>IN</sub> = 12 V, I <sub>LOAD</sub> = 500 mA		90%						

<sup>(1)</sup> All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

(2) Typical numbers are at 25°C and represent the most likely norm.

#### 7.7 Electrical Characteristics – 12 V

Specifications are for  $T_{.l} = 25^{\circ}C$  (unless otherwise noted).

P	ARAMETER	TEST CO	MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT				
SYSTEM PARAMETERS (3)										
		V 45 V to 40 V	T <sub>J</sub> = 25°C	11.82	12 12	12.18				
V <sub>OUT</sub>	Output voltage	$V_{IN} = 15 \text{ V to } 40 \text{ V},$ $I_{LOAD} = 20 \text{ mA to } 500 \text{ mA}$	Over full operating temperature range	11.64		12.36	V			
η	Efficiency	V <sub>IN</sub> = 24 V, I <sub>LOAD</sub> = 500 mA		94%						

<sup>(1)</sup> All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

(2) Typical numbers are at 25°C and represent the most likely norm.

<sup>(3)</sup> External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2671 is used as shown in Figure 15 and Figure 21 test circuits, system performance is as specified by the system parameters section of the *Electrical Characteristics*.

<sup>(3)</sup> External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2671 is used as shown in Figure 15 and Figure 21 test circuits, system performance is as specified by the system parameters section of the *Electrical Characteristics*.

<sup>(3)</sup> External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2671 is used as shown in Figure 15 and Figure 21 test circuits, system performance is as specified by the system parameters section of the *Electrical Characteristics*.



# 7.8 Electrical Characteristics – Adjustable

Specifications are for  $T_1 = 25$ °C (unless otherwise noted).

ı	PARAMETER	TEST CONDITIONS		MIN <sup>(1)</sup>	TYP <sup>(2)</sup>	MAX <sup>(1)</sup>	UNIT
SYST	EM PARAMETERS	S <sup>(3)</sup>					
		V <sub>IN</sub> = 8 V to 40 V,	T <sub>J</sub> = 25°C	1.192	1.21	1.246 1 1.228	
	Feedback	I <sub>LOAD</sub> = 20 mA to 500 mA V <sub>OUT</sub> programmed for 5 V	Over full operating temperature range	1.174		1.246	V
$V_{FB}$	voltage	V <sub>IN</sub> = 6.5 V to 40 V,	T <sub>J</sub> = 25°C	1.192	1.21	1.228	
		$I_{LOAD}$ = 20 mA to 250 mA Over full operating temperature range		1.174		1.246	V
η	Efficiency	V <sub>IN</sub> = 12 V, I <sub>LOAD</sub> = 500 mA	/ <sub>IN</sub> = 12 V, I <sub>LOAD</sub> = 500 mA		90%		

<sup>(1)</sup> All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

(2) Typical numbers are at 25°C and represent the most likely norm.

# 7.9 Electrical Characteristics – All Output Voltage Versions

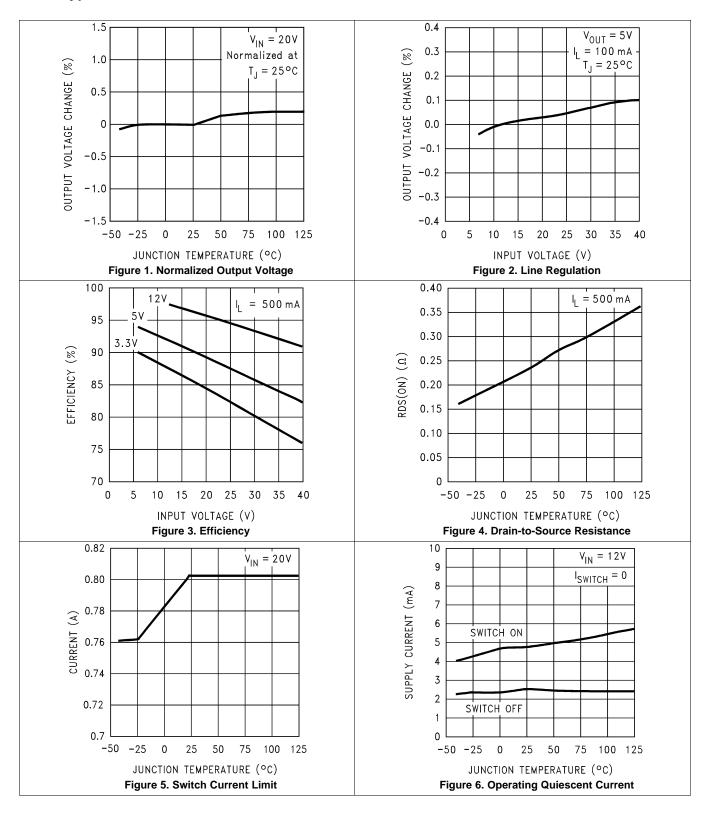
Specifications are for  $T_J = 25^{\circ}C$ ,  $V_{IN} = 12$  V for the 3.3-V, 5-V, and Adjustable versions and  $V_{IN} = 24$  V for the 12-V version, and  $I_{I,OAD} = 100$  mA (unless otherwise noted).

	PARAMETERS	TES	ST CONDITIONS	MIN	TYP	MAX	UNIT	
DEVICE	PARAMETERS							
	Outcomet surrent	V <sub>FEEDBACK</sub> = 8 V for 3.3-V, 5-V, and adjustable	e versions		2.5	3.6	A	
IQ	Quiescent current	V <sub>FEEDBACK</sub> = 15 V for 12-V versions			2.5		mA.	
			T <sub>J</sub> = 25°C		50	100		
I <sub>STBY</sub>	Standby quiescent current	ON/OFF pin = 0 V	Over full operating temperature range			150	μА	
	Current limit	T <sub>J</sub> = 25°C		0.62	0.8	1.2	^	
I <sub>CL</sub>	Current limit	Over full operating temperatu	ure range	0.575		1.25	Α	
I <sub>L</sub> Output leakage current		V <sub>IN</sub> = 40 V, ON/ <del>OFF</del> pin = 0 V V <sub>SWITCH</sub> = 0 V	V		1	25	μА	
-	, ,	V <sub>SWITCH</sub> = −1 V, ON/OFF pin	= 0 V		6	15	mA	
R <sub>DS(ON)</sub>	Switch ON-resistance		T <sub>J</sub> = 25°C		0.25	0.4		
		I <sub>SWITCH</sub> = 500 mA	Over full operating temperature range			0.6	Ω	
				$T_J = 25^{\circ}C$		260		
$f_O$	Oscillator frequency	Measured at switch pin	Over full operating temperature range	225		275	kHz	
D	Maximum duty cycle				95%			
U	Minimum duty cycle				0%			
I <sub>BIAS</sub>	Feedback bias current	V <sub>FEEDBACK</sub> = 1.3 V (adjustable	e version only)		85		nA	
V	ON/OFF pin voltage thresholds	$T_J = 25^{\circ}C$			1.4		V	
V <sub>S/D</sub>	ON/OFF pill voltage tillesilolus	Over full operating temperatu	ure range	0.8		2	V	
			$T_J = 25^{\circ}C$		20			
I <sub>S/D</sub>	ON/OFF pin current	ON/OFF pin = 0 V	Over full operating temperature range	7		37	μА	
F <sub>SYNC</sub>	Synchronization frequency	V <sub>SYNC</sub> = 3.5 V, 50% duty cycle			400		kHz	
$V_{SYNC}$	Synchronization threshold voltage				1.4		V	
V	Soft-start voltage	$T_J = 25^{\circ}C$			0.63		V	
V <sub>SS</sub>	Soit-start voltage	Over full operating temperatu	ure range	0.53		0.73	v	
laa -	Soft-start current	T <sub>J</sub> = 25°C			4.5		μА	
I <sub>SS</sub>	Joil-staft Culterit	Over full operating temperatu	ure range	1.5		6.9	μА	

 <sup>(3)</sup> External components such as the catch diode, inductor, input and output capacitors, and voltage programming resistors can affect switching regulator performance. When the LM2671 is used as shown in Figure 15 and Figure 21 test circuits, system performance is as specified by the system parameters section of the *Electrical Characteristics*.

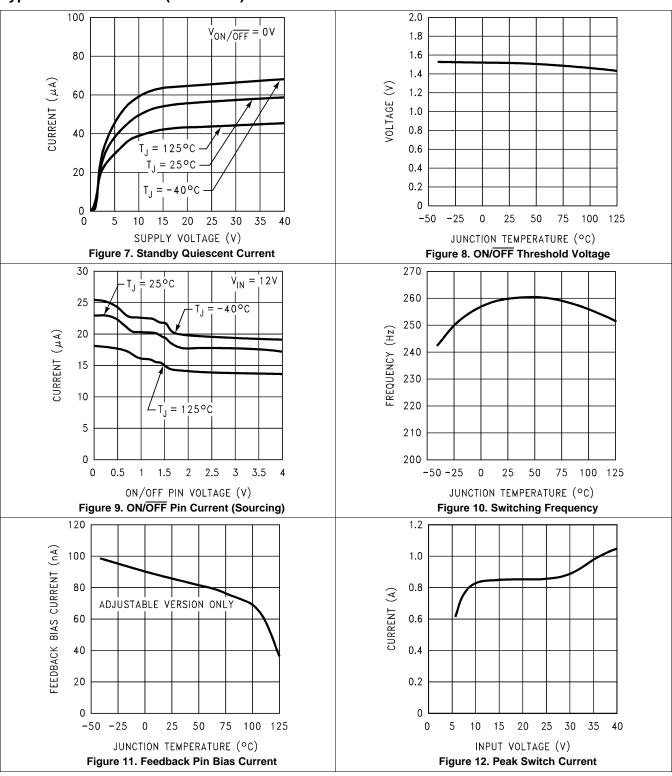


# 7.10 Typical Characteristics



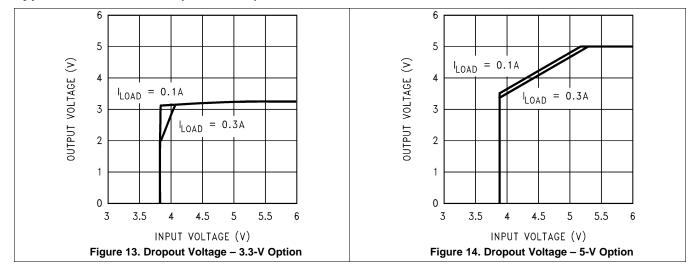
# TEXAS INSTRUMENTS

# **Typical Characteristics (continued)**





# **Typical Characteristics (continued)**





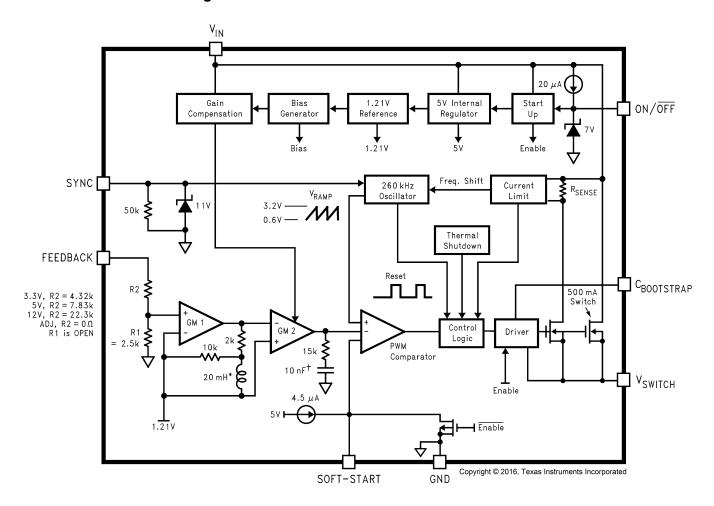
# 8 Detailed Description

#### 8.1 Overview

The LM2671 provides all of the active functions required for a step-down (buck) switching regulator. The internal power switch is a DMOS power MOSFET to provide power supply designs with high current capability, up to 0.5 A, and highly efficient operation.

The LM2671 is part of the SIMPLE SWITCHER® family of power converters. A complete design uses a minimum number of external components, which have been predetermined from a variety of manufacturers. Using either this data sheet or TI's WEBENCH® design tool, a complete switching power supply can be designed quickly. Also, see *LM2670 SIMPLE SWITCHER® High Efficiency 3A Step-Down Voltage Regulator with Sync* for additional applications information.

# 8.2 Functional Block Diagram



# 8.3 Feature Description

# 8.3.1 Switch Output

This is the output of a power MOSFET switch connected directly to the input voltage. The switch provides energy to an inductor, an output capacitor and the load circuitry under control of an internal pulse-width-modulator (PWM). The PWM controller is internally clocked by a fixed 260-kHz oscillator. In a standard step-down application the duty cycle (Time ON/Time OFF) of the power switch is proportional to the ratio of the power supply output voltage to the input voltage. The voltage on the  $V_{SW}$  pin cycles between  $V_{IN}$  (switch ON) and below ground by the voltage drop of the external Schottky diode (switch OFF).



#### **Feature Description (continued)**

#### 8.3.2 Input

The input voltage for the power supply is connected to the  $V_{IN}$  pin. In addition to providing energy to the load the input voltage also provides bias for the internal circuitry of the LM2671. For ensured performance the input voltage must be in the range of 6.5 V to 40 V. For best performance of the power supply the  $V_{IN}$  pin must always be bypassed with an input capacitor placed close to this pin and GND.

#### 8.3.3 C Boost

A capacitor must be connected from the  $C_B$  pin to the  $V_{SW}$  pin. This capacitor boosts the gate drive to the internal MOSFET above  $V_{IN}$  to fully turn it ON. This minimizes conduction losses in the power switch to maintain high efficiency. The recommended value for C Boost is 0.01  $\mu$ F.

#### 8.3.4 **Ground**

This is the ground reference connection for all components in the power supply. In fast-switching, high-current applications such as those implemented with the LM2671, TI recommends that a broad ground plane be used to minimize signal coupling throughout the circuit.

# 8.3.5 Sync

This input allows control of the switching clock frequency. If left open-circuited the regulator is switched at the internal oscillator frequency, typically 260 kHz. An external clock can be used to force the switching frequency and thereby control the output ripple frequency of the regulator. This capability provides for consistent filtering of the output ripple from system to system as well as precise frequency spectrum positioning of the ripple frequency which is often desired in communications and radio applications. This external frequency must be greater than the LM2671 internal oscillator frequency, which could be as high as 275 kHz, to prevent an erroneous reset of the internal ramp oscillator and PWM control of the power switch. The ramp oscillator is reset on the positive going edge of the sync input signal. TI recommends that the external TTL or CMOS compatible clock (between 0 V and a level greater than 3 V) be ac coupled to the SYNC pin through a 100-pF capacitor and a 1-k $\Omega$  resistor to ground.

When the SYNC function is used, current limit frequency foldback is not active. Therefore, the device may not be fully protected against extreme output short-circuit conditions.

#### 8.3.6 Feedback

This is the input to a two-stage high gain amplifier, which drives the PWM controller. Connect the FB pin directly to the output for proper regulation. For the fixed output devices (3.3-V, 5-V and 12-V outputs), a direct wire connection to the output is all that is required as internal gain setting resistors are provided inside the LM2671. For the adjustable output version two external resistors are required to set the DC output voltage. For stable operation of the power supply it is important to prevent coupling of any inductor flux to the feedback input.

#### 8.3.7 ON/OFF

This input provides an electrical ON/OFF control of the power supply. Connecting this pin to ground or to any voltage less than 0.8 V is completely turn OFF the regulator. The current drain from the input supply when OFF is only 50  $\mu$ A. The ON/OFF input has an internal pullup current source of approximately 20  $\mu$ A and a protection clamp Zener diode of 7 V to ground. When electrically driving the ON/OFF pin the high voltage level for the ON condition must not exceed the 6 V absolute maximum limit. When ON/OFF control is not required this pin must be left open.

#### 8.4 Device Functional Modes

#### 8.4.1 Shutdown Mode

The ON/ $\overline{\text{OFF}}$  pin provides electrical ON and OFF control for the LM2671. When the voltage of this pin is lower than 1.4 V, the device enters shutdown mode. The typical standby current in this mode is 50  $\mu$ A.



# **Device Functional Modes (continued)**

# 8.4.2 Active Mode

When the voltage of the ON/OFF pin is higher than 1.4 V, the device starts switching and the output voltage rises until it reaches a normal regulation voltage.



# 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

# 9.1 Application Information

The LM2671 is a step-down DC-DC regulator. The device is typically used to convert a higher DC voltage to a lower DC voltage with a maximum output current of 0.5 A. The following design procedure can be used to select components for the LM2671. Alternately, the WEBENCH® software may be used to generate complete designs. When generating a design, the WEBENCH software uses iterative design procedure and accesses comprehensive databases of components. See ti.com for more details.

When the output voltage is greater than approximately 6 V, and the duty cycle at minimum input voltage is greater than approximately 50%, the designer must exercise caution in selection of the output filter components. When an application designed to these specific operating conditions is subjected to a current limit fault condition, it may be possible to observe a large hysteresis in the current limit. This can affect the output voltage of the device until the load current is reduced sufficiently to allow the current limit protection circuit to reset itself.

Under current limiting conditions, the LM267x is designed to respond in the following manner:

- 1. At the moment when the inductor current reaches the current limit threshold, the ON-pulse is immediately terminated. This happens for any application condition.
- 2. However, the current limit block is also designed to momentarily reduce the duty cycle to below 50% to avoid subharmonic oscillations, which could cause the inductor to saturate.
- 3. Therefore, once the inductor current falls below the current limit threshold, there is a small relaxation time during which the duty cycle progressively rises back above 50% to the value required to achieve regulation.

If the output capacitance is sufficiently *large*, it might be possible that as the output tries to recover, the output capacitor charging current is large enough to repeatedly re-trigger the current limit circuit before the output has fully settled. This condition is exacerbated with higher output voltage settings because the energy requirement of the output capacitor varies as the square of the output voltage (½ CV2), thus requiring an increased charging current. A simple test to determine if this condition might exist for a suspect application is to apply a short circuit across the output of the converter, and then remove the shorted output condition. In an application with properly selected external components, the output recovers smoothly. Practical values of external components that have been experimentally found to work well under these specific operating conditions are  $C_{OUT} = 47 \mu F$ ,  $L = 22 \mu H$ .

# NOTE

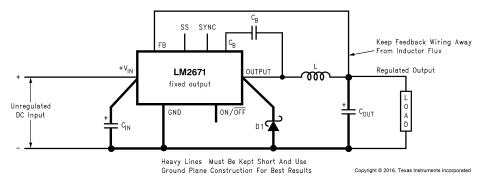
Even with these components, for a device's current limit of ICLIM, the maximum load current under which the possibility of the large current limit hysteresis can be minimized is ICLIM/2.

For example, if the input is 24 V and the set output voltage is 18 V, then for a desired maximum current of 1.5 A, the current limit of the chosen switcher must be confirmed to be at least 3 A. Under extreme overcurrent or short-circuit conditions, the LM267X employs frequency foldback in addition to the current limit. If the cycle-by-cycle inductor current increases above the current limit threshold (due to short circuit or inductor saturation for example) the switching frequency is automatically reduced to protect the IC. Frequency below 100 kHz is typical for an extreme short-circuit condition.



# 9.2 Typical Applications

# 9.2.1 Fixed Output Voltage Version



 $C_{IN}$  = 22- $\mu$ F, 50-V Tantalum, Sprague 199D Series  $C_{OUT}$  = 47- $\mu$ F, 25-V Tantalum, Sprague 595D Series D1 = 3.3-A, 50-V Schottky Rectifier, IR 30WQ05F L1 = 68- $\mu$ H Sumida #RCR110D-680L

 $C_B = 0.01 - \mu F$ , 50-V ceramic

Figure 15. Typical Application for Fixed Output Voltage Versions

#### 9.2.1.1 Design Requirements

Table 1 lists the design parameters for this example.

PARAMETER

Regulated output voltage (3.3 V, 5 V, or 12 V), V<sub>OUT</sub>

Maximum DC input voltage, V<sub>IN</sub>(max)

Maximum load current, I<sub>I OAD</sub>(max)

500 mA

**Table 1. Design Parameters** 

#### 9.2.1.2 Detailed Design Procedure

#### 9.2.1.2.1 Inductor Selection (L1)

- 1. Select the correct inductor value selection guide from Figure 17 and Figure 18 or Figure 19 (output voltages of 3.3 V, 5 V, or 12 V respectively). For all other voltages, see the design procedure for the adjustable version. Use the inductor selection guide for the 5-V version shown in Figure 18.
- From the inductor value selection guide, identify the inductance region intersected by the maximum input voltage line and the maximum load current line. Each region is identified by an inductance value and an inductor code (LXX). From the inductor value selection guide shown in Figure 18, the inductance region intersected by the 12-V horizontal line and the 500-mA vertical line is 47 μH, and the inductor code is L13.
- 3. Select an appropriate inductor from the four manufacturer's part numbers listed in Table 2. Each manufacturer makes a different style of inductor to allow flexibility in meeting various design requirements. See the following for some of the differentiating characteristics of each manufacturer's inductors:
  - Schottky: ferrite EP core inductors; these have very low leakage magnetic fields to reduce electromagnetic interference (EMI) and are the lowest power loss inductors
  - Renco: ferrite stick core inductors; benefits are typically lowest cost inductors and can withstand E•T and transient peak currents above rated value. Be aware that these inductors have an external magnetic field which may generate more EMI than other types of inductors.
  - Pulse: powered iron toroid core inductors; these can also be low cost and can withstand larger than normal E•T and transient peak currents. Toroid inductors have low EMI.
  - Coilcraft: ferrite drum core inductors; these are the smallest physical size inductors, available only as SMT components. Be aware that these inductors also generate EMI—but less than stick inductors.

Complete specifications for these inductors are available from the respective manufacturers.



The inductance value required is  $47 \mu H$ . From the table in Table 2, go to the L13 line and choose an inductor part number from any of the four manufacturers shown. In most instances, both through hole and surface mount inductors are available.

**Table 2. Inductor Manufacturers' Part Numbers** 

IND.	INDUCTANCE	CURRENT	SCHO <sup>*</sup>	TTKY	RENO	o	PULSE EN	NGINEERING	COILCRAFT
REF. DESG.	(μH)	(A)	THROUGH HOLE	SURFACE MOUNT	THROUGH HOLE	SURFACE MOUNT	THROUGH HOLE	SURFACE MOUNT	SURFACE MOUNT
L2	150	0.21	67143920	67144290	RL-5470-4	RL1500-150	PE-53802	PE-53802-S	DO1608-154
L3	100	0.26	67143930	67144300	RL-5470-5	RL1500-100	PE-53803	PE-53803-S	DO1608-104
L4	68	0.32	67143940	67144310	RL-1284-68-43	RL1500-68	PE-53804	PE-53804-S	DO1608-683
L5	47	0.37	67148310	67148420	RL-1284-47-43	RL1500-47	PE-53805	PE-53805-S	DO1608-473
L6	33	0.44	67148320	67148430	RL-1284-33-43	RL1500-33	PE-53806	PE-53806-S	DO1608-333
L7	22	0.52	67148330	67148440	RL-1284-22-43	RL1500-22	PE-53807	PE-53807-S	DO1608-223
L9	220	0.32	67143960	67144330	RL-5470-3	RL1500-220	PE-53809	PE-53809-S	DO3308-224
L10	150	0.39	67143970	67144340	RL-5470-4	RL1500-150	PE-53810	PE-53810-S	DO3308-154
L11	100	0.48	67143980	67144350	RL-5470-5	RL1500-100	PE-53811	PE-53811-S	DO3308-104
L12	68	0.58	67143990	67144360	RL-5470-6	RL1500-68	PE-53812	PE-53812-S	DO3308-683
L13	47	0.7	67144000	67144380	RL-5470-7	RL1500-47	PE-53813	PE-53813-S	DO3308-473
L14	33	0.83	67148340	67148450	RL-1284-33-43	RL1500-33	PE-53814	PE-53814-S	DO3308-333
L15	22	0.99	67148350	67148460	RL-1284-22-43	RL1500-22	PE-53815	PE-53815-S	DO3308-223
L18	220	0.55	67144040	67144420	RL-5471-2	RL1500-220	PE-53818	PE-53818-S	DO3316-224
L19	150	0.66	67144050	67144430	RL-5471-3	RL1500-150	PE-53819	PE-53819-S	DO3316-154
L20	100	0.82	67144060	67144440	RL-5471-4	RL1500-100	PE-53820	PE-53820-S	DO3316-104
L21	68	0.99	67144070	67144450	RL-5471-5	RL1500-68	PE-53821	PE-53821-S	DO3316-683

#### 9.2.1.2.2 Output Capacitor Selection (C<sub>OUT</sub>)

Select an output capacitor from the output capacitor table in Table 9. Using the output voltage and the inductance value found in the inductor selection guide, step 1, locate the appropriate capacitor value and voltage rating.

Use the 5-V section in the output capacitor table in Table 9. Choose a capacitor value and voltage rating from the line that contains the inductance value of 47  $\mu$ H. The capacitance and voltage rating values corresponding to the 47- $\mu$ H inductor are:

- Surface mount:
  - 68-μF, 10-V Sprague 594D series
  - 100-μF, 10-V AVX TPS series
- Through hole:
  - 68-μF, 10-V Sanyo OS-CON SA series
  - 150-μF, 35-V Sanyo MV-GX series
  - 150-μF, 35-V Nichicon PL series
  - 150-μF, 35-V Panasonic HFQ series

The capacitor list contains through-hole electrolytic capacitors from four different capacitor manufacturers and surface mount tantalum capacitors from two different capacitor manufacturers. TI recommends that both the manufacturers and the manufacturer's series that are listed in the table be used.



#### **Table 3. Output Capacitor Table**

				OUTPUT CA	APACITOR				
OUTPUT	INDUCTANCE	SURFACE	MOUNT	THROUGH HOLE					
VOLTAGE (V)	(μH)	SPRAGUE 594D SERIES (μF/V)	AVX TPS SERIES (μF/V)	SANYO OS-CON SA SERIES (μF/V)	SANYO MV-GX SERIES (μF/V)	NICHICON PL SERIES (μF/V)	PANASONIC HFQ SERIES (μF/V)		
	22	120/6.3	100/10	100/10	330/35	330/35	330/35		
	33	120/6.3	100/10	68/10	220/35	220/35	220/35		
0.0	47	68/10	100/10	68/10	150/35	150/35	150/35		
3.3	68	120/6.3	100/10	100/10	120/35	120/35	120/35		
	100	120/6.3	100/10	100/10	120/35	120/35	120/35		
	150	120/6.3	100/10	100/10	120/35	120/35	120/35		
	22	100/16	100/10	100/10	330/35	330/35	330/35		
	33	68/10	10010	68/10	220/35	220/35	220/35		
_	47	68/10	100/10	68/10	150/35	150/35	150/35		
5	68	100/16	100/10	100/10	120/35	120/35	120/35		
	100	100/16	100/10	100/10	120/35	120/35	120/35		
	150	100/16	100/10	100/10	120/35	120/35	120/35		
	22	120/20	(2x) 68/20	68/20	330/35	330/35	330/35		
	33	68/25	68/20	68/20	220/35	220/35	220/35		
	47	47/20	68/20	47/20	150/35	150/35	150/35		
12	68	47/20	68/20	47/20	120/35	120/35	120/35		
	100	47/20	68/20	47/20	120/35	120/35	120/35		
	150	47/20	68/20	47/20	120/35	120/35	120/35		
	220	47/20	68/20	47/20	120/35	120/35	120/35		

#### 9.2.1.2.3 Catch Diode Selection (D1)

- 1. In normal operation, the average current of the catch diode is the load current times the catch diode duty cycle, 1-D (D is the switch duty cycle, which is approximately the output voltage divided by the input voltage). The largest value of the catch diode average current occurs at the maximum load current and maximum input voltage (minimum D). For normal operation, the catch diode current rating must be at least 1.3 times greater than its maximum average current. However, if the power supply design must withstand a continuous output short, the diode must have a current rating equal to the maximum current limit of the LM2671. The most stressful condition for this diode is a shorted output condition (refer to Table 4). In this example, a 1-A, 20-V Schottky diode provides the best performance. If the circuit must withstand a continuous shorted output, TI recommends a higher-current Schottky diode.
- 2. The reverse voltage rating of the diode must be at least 1.25 times the maximum input voltage.
- 3. Because of their fast switching speed and low forward voltage drop, Schottky diodes provide the best performance and efficiency. This Schottky diode must be placed close to the LM2671 using short leads and short printed-circuit traces.



Table 4. Schottky Diode Selection Table

V	1-A DI	ODES	3-A DI	ODES	
V <sub>R</sub>	SURFACE MOUNT	THROUGH HOLE	SURFACE MOUNT	THROUGH HOLE	
20.1/	SK12	1N5817	SK32	1N5820	
20 V	B120	SR102		SR302	
	SK13	1N5818	SK33	1N5821	
30 V	B130	11DQ03	30WQ03F	31DQ03	
	MBRS130	SR103	_	_	
	SK14	1N5819	SK34	1N5822	
	B140	11DQ04	30BQ040	MBR340	
40.1/	MBRS140	SR104	30WQ04F	31DQ04	
40 V	10BQ040	_	MBRS340	SR304	
	10MQ040	_	MBRD340	_	
	15MQ040	_	_	_	
	SK15	MBR150	SK35	MBR350	
50 V	B150	11DQ05	30WQ05F	31DQ05	
	10BQ050	SR105	_	SR305	

#### 9.2.1.2.4 Input Capacitor (C<sub>IN</sub>)

A low ESR aluminum or tantalum bypass capacitor is required between the input pin and ground to prevent large voltage transients from appearing at the input. This capacitor must be placed close to the IC using short leads. In addition, the RMS current rating of the input capacitor must be selected to be at least ½ the DC load current. The capacitor manufacturer data sheet must be checked to assure that this current rating is not exceeded. The curves shown in Figure 16 show typical RMS current ratings for several different aluminum electrolytic capacitor values. A parallel connection of two or more capacitors may be required to increase the total minimum RMS current rating to suit the application requirements.

For an aluminum electrolytic capacitor, the voltage rating must be at least 1.25 times the maximum input voltage. Caution must be exercised if solid tantalum capacitors are used. The tantalum capacitor voltage rating must be twice the maximum input voltage. Table 5 and Table 6 show the recommended application voltage for AVX TPS and Sprague 594D tantalum capacitors. TI also recommends that they be surge current tested by the manufacturer. The TPS series available from AVX, and the 593D and 594D series from Sprague are all surge current tested. Another approach to minimize the surge current stresses on the input capacitor is to add a small inductor in series with the input supply line.

Table 5. AVX TPS

RECOMMENDED APPLICATION VOLTAGE	VOLTAGE RATING					
85°C RATING						
3.3	6.3					
5	10					
10	20					
12	25					
15	35					

Table 6. Sprague 594D

RECOMMENDED APPLICATION VOLTAGE	VOLTAGE RATING
85°C F	RATING
2.5	4
3.3	6.3
5	10
8	16
12	20
18	25
24	35
29	50

Use caution when using ceramic capacitors for input bypassing, because it may cause severe ringing at the  $V_{IN}$  pin. The important parameters for the input capacitor are the input voltage rating and the RMS current rating. With a maximum input voltage of 12 V, an aluminum electrolytic capacitor with a voltage rating greater than 15 V (1.25 ×  $V_{IN}$ ) is required. The next higher capacitor voltage rating is 16 V.

The RMS current rating requirement for the input capacitor in a buck regulator is approximately ½ the DC load current. In this example, with a 500-mA load, a capacitor with a RMS current rating of at least 250 mA is required. The curves shown in Figure 16 can be used to select an appropriate input capacitor. From the curves, locate the 16-V line and note which capacitor values have RMS current ratings greater than 250 mA.

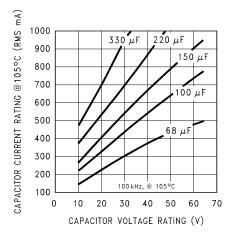


Figure 16. RMS Current Ratings for Low ESR Electrolytic Capacitors (Typical)

For a through-hole design, a  $100-\mu F$ , 16-V electrolytic capacitor (Panasonic HFQ series, Nichicon PL, Sanyo MV-GX series or equivalent) would be adequate. Other types or other manufacturers' capacitors can be used provided the RMS ripple current ratings are adequate. Additionally, for a complete surface mount design, electrolytic capacitors such as the Sanyo CV-C or CV-BS and the Nichicon WF or UR and the NIC Components NACZ series could be considered.

For surface mount designs, solid tantalum capacitors can be used, but caution must be exercised with regard to the capacitor surge current rating and voltage rating. In this example, checking the Sprague 594D series datasheet, a Sprague 594D 15-μF, 25-V capacitor is adequate.

#### 9.2.1.2.5 Boost Capacitor (C<sub>B</sub>)

This capacitor develops the necessary voltage to turn the switch gate on fully. All applications must use a 0.01- $\mu$ F, 50-V ceramic capacitor. For this application, and all applications, use a 0.01- $\mu$ F, 50-V ceramic capacitor.

(1)



#### 9.2.1.2.6 Soft-Start Capacitor (C<sub>SS</sub>) - Optional

This capacitor controls the rate at which the device starts up. The formula for the soft-start capacitor  $C_{SS}$  is Equation 1.

$$C_{SS} \approx (I_{SS} \cdot t_{SS}) / [V_{SSTH} + 2.6V \cdot (\frac{V_{OUT} + V_{SCHOTTKY}}{V_{IN}})]$$

#### where

- I<sub>SS</sub>= soft-start current (4.5 μA typical)
- t<sub>SS</sub>= soft-start time (selected)
- V<sub>SSTH</sub>= soft-start threshold voltage (0.63 V typical)
- V<sub>OUT</sub>= output voltage (selected)
- V<sub>SCHOTTKY</sub>= schottky diode voltage drop (0.4 V typical)

For this application, selecting a start-up time of 10 ms and using Equation 2 for C<sub>SS</sub>.

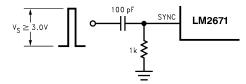
$$C_{SS} \approx (4.5 \ \mu\text{A} \cdot 10 \ \text{ms}) / [0.63\text{V} + 2.6\text{V} \cdot (\frac{5\text{V} + 0.4\text{V}}{12\text{V}})]$$
  
= 25 nF  $\approx 0.022 \ \mu\text{F}$ . (2)

If this feature is not desired, leave this pin open. With certain soft-start capacitor values and operating conditions, the LM2671 can exhibit an overshoot on the output voltage during turnon. Especially when starting up into no load or low load, the soft-start function may not be effective in preventing a larger voltage overshoot on the output. With larger loads or lower input voltages during start-up this effect is minimized. In particular, avoid using soft-start capacitors between  $0.033~\mu F$  and  $1~\mu F$ .

# 9.2.1.2.7 Frequency Synchronization (optional)

The LM2671 (oscillator) can be synchronized to run with an external oscillator, using the sync pin (pin 3). By doing so, the LM2671 can be operated at higher frequencies than the standard frequency of 260 kHz. This allows for a reduction in the size of the inductor and output capacitor.

As shown in the drawing below, a signal applied to a RC filter at the sync pin causes the device to synchronize to the frequency of that signal. For a signal with a peak-to-peak amplitude of 3 V or greater, a  $1-k\Omega$  resistor and a 100-pF capacitor are suitable values.

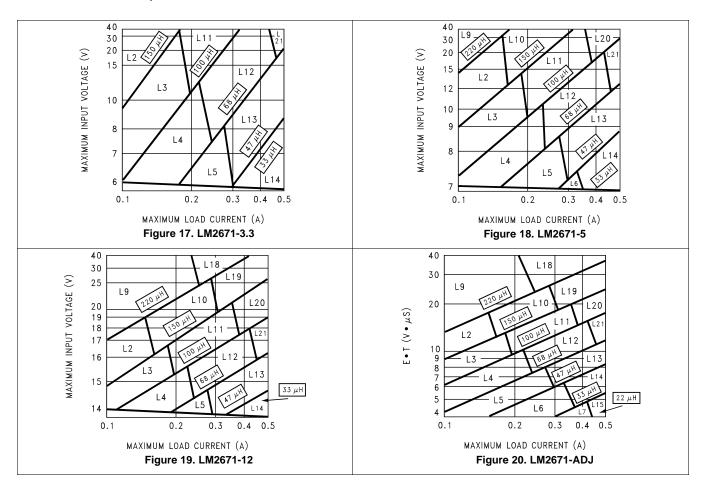


For all applications, use a 1-k $\Omega$  resistor and a 100-pF capacitor for the RC filter.



### 9.2.1.3 Application Curves

for continuous mode operation



# 9.2.2 Adjustable Output Voltage Version

Locate the Programming Resistors near the Feedback Pin Using Short Leads

R1

R2

SS SYNC

GND

ON/OFF

Heavy Lines Must Be Kept Short And Use
Ground Plane Construction For Best Results

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 $C_{IN}$  = 22-μF, 50-V Tantalum, Sprague 199D Series  $C_{OUT}$  = 47-μF, 25-V Tantalum, Sprague 595D Series D1 = 3.3-A, 50-V Schottky Rectifier, IR 30WQ05F L1 = 68-μH Sumida #RCR110D-680L R1 =1.5 kΩ, 1%

Figure 21. Typical Application for Adjustable Output Voltage Versions

20

 $C_B = 0.01 - \mu F$ , 50-V ceramic



### 9.2.2.1 Design Requirements

Table 7 lists the design parameters for this example.

**Table 7. Design Parameters** 

PARAMETER	VALUE
Regulated output voltage, V <sub>OUT</sub>	20 V
Maximum input voltage, V <sub>IN</sub> (max)	28 V
Maximum load current, I <sub>LOAD</sub> (max)	500 mA
Switching frequency, F	Fixed at a nominal 260 kHz

#### 9.2.2.2 Detailed Design Procedure

#### 9.2.2.2.1 Programming Output Voltage

Select R<sub>1</sub> and R<sub>2</sub>, as shown in Figure 21.

Use the following formula to select the appropriate resistor values.

$$V_{OUT} = V_{REF} \left( 1 + \frac{R_2}{R_1} \right)$$

where

• 
$$V_{REF} = 1.21 \text{ V}$$
 (3)

Select  $R_1$  to be 1 k $\Omega$ , 1%. Solve for  $R_2$ .

$$R_2 = R_1 \left( \frac{V_{OUT}}{V_{REF}} - 1 \right) = 1 \text{ k}\Omega \left( \frac{20V}{1.23V} - 1 \right)$$
(4)

Select a value for  $R_1$  between 240  $\Omega$  and 1.5 k $\Omega$ . The lower resistor values minimize noise pickup in the sensitive feedback pin. For the lowest temperature coefficient and the best stability with time, use 1% metal film resistors.

$$R_2 = R_1 \left( \frac{V_{OUT}}{V_{REF}} - 1 \right) \tag{5}$$

 $R_2$  = 1 kΩ (16.53 - 1) = 15.53 kΩ, closest 1% value is 15.4 kΩ.

 $R_2 = 15.4 \text{ k}\Omega.$ 

#### 9.2.2.2.2 Inductor Selection (L1)

Calculate the inductor Volt • microsecond constant E • T (V • μs) from Equation 6.

$$E \cdot T = (V_{IN(MAX)} - V_{OUT} - V_{SAT}) \cdot \frac{V_{OUT} + V_D}{V_{IN(MAX)} - V_{SAT} + V_D} \cdot \frac{1000}{260} (V \cdot \mu s)$$

where

V<sub>SAT</sub> = internal switch saturation voltage = 0.25 V

Calculate the inductor Volt • microsecond constant (E • T) with Equation 7.

$$E \cdot T = (28 - 20 - 0.25) \cdot \frac{20 + 0.5}{28 - 0.25 + 0.5} \cdot \frac{1000}{260} (V \cdot \mu s)$$

$$E \cdot T = (7.75) \cdot \frac{20.5}{28.25} \cdot 3.85 (V \cdot \mu s) = 21.6 (V \cdot \mu s)$$
(7)

2. Use the E • T value from the previous formula and match it with the E • T number on the vertical axis of the inductor value selection guide shown in Figure 20.

$$E \bullet T = 21.6 \text{ (V} \bullet \mu \text{s)} \tag{8}$$

3. On the horizontal axis, select the maximum load current in Equation 9.

$$I_{LOAD}(max) = 500 \text{ mA}$$

- 4. Identify the inductance region intersected by the E T value and the maximum load current value. Each region is identified by an inductance value and an inductor code (LXX). From the inductor value selection guide shown in Figure 20, the inductance region intersected by the 21.6 (V μs) horizontal line and the 500-mA vertical line is 100 μH, and the inductor code is L20.
- 5. Select an appropriate inductor from the four manufacturer's part numbers listed in Table 2. For information

(6)



on the different types of inductors, see the inductor selection in the fixed output voltage design procedure. From the table in Table 2, locate line L20, and select an inductor part number from the list of manufacturers' part numbers.

#### 9.2.2.2.3 Output Capacitor Selection (C<sub>OUT</sub>)

- 1. Select an output capacitor from the capacitor code selection guide in Table 8. Using the inductance value found in the inductor selection guide, step 1, locate the appropriate capacitor code corresponding to the desired output voltage. Use the appropriate row of the capacitor code selection guide, in Table 8. For this example, use the 15-V to 20-V row. The capacitor code corresponding to an inductance of 100 μH is C20.
- 2. Select an appropriate capacitor value and voltage rating, using the capacitor code, from the output capacitor selection table in Table 9. There are two solid tantalum (surface mount) capacitor manufacturers and four electrolytic (through hole) capacitor manufacturers to choose from. TI recommends using the manufacturers and the manufacturer's series that are listed in the table.

From the output capacitor selection table in Table 9, choose a capacitor value (and voltage rating) that intersects the capacitor code(s) selected in section A, C20.

The capacitance and voltage rating values corresponding to the capacitor code C20 are:

- Surface mount:
  - 33-μF, 25-V Sprague 594D series
  - 33-μF, 25-V AVX TPS series
- Through hole:
  - 33-μF, 25-V Sanyo OS-CON SC series
  - 120-μF, 35-V Sanyo MV-GX series
  - 120-μF, 35-V Nichicon PL series
  - 120-μF, 35-V Panasonic HFQ series

Other manufacturers or other types of capacitors may also be used, provided the capacitor specifications (especially the 100-kHz ESR) closely match the characteristics of the capacitors listed in the output capacitor table. See the capacitor manufacturers' data sheet for this information.

**Table 8. Capacitor Code Selection Guide** 

CASE	OUTPUT	INDUCTANCE (μH)								
STYLE (1)	VOLTAGE (V)	22	33	47	68	100	150	220		
SM and TH	1.21–2.5	_	_	_	_	C1	C2	C3		
SM and TH	2.5–3.75	_	_	_	C1	C2	C3	C3		
SM and TH	3.75–5	_	_	C4	C5	C6	C6	C6		
SM and TH	5–6.25	_	C4	C7	C6	C6	C6	C6		
SM and TH	6.25–7.5	C8	C4	C7	C6	C6	C6	C6		
SM and TH	7.5–10	C9	C10	C11	C12	C13	C13	C13		
SM and TH	10–12.5	C14	C11	C12	C12	C13	C13	C13		
SM and TH	12.5–15	C15	C16	C17	C17	C17	C17	C17		
SM and TH	15–20	C18	C19	C20	C20	C20	C20	C20		
SM and TH	20–30	C21	C22	C22	C22	C22	C22	C22		
TH	30–37	C23	C24	C24	C25	C25	C25	C25		

(1) SM - Surface Mount, TH - Through Hole



Table 9. Output Capacitor Selection Table

	OUTPUT CAPACITOR								
CAP.	SURFAC	E MOUNT		THROUGH	HOLE				
REF. DESG. #	SPRAGUE 594D SERIES (μF/V)	AVX TPS SERIES (μF/V)	SANYO OS-CON SA SERIES (μF/V)	SANYO MV-GX SERIES (μF/V)	NICHICON PL SERIES (μF/V)	PANASONIC HFQ SERIES (μF/V)			
C1	120/6.3	100/10	100/10	220/35	220/35	220/35			
C2	120/6.3	100/10	100/10	150/35	150/35	150/35			
C3	120/6.3	100/10	100/35	120/35	120/35	120/35			
C4	68/10	100/10	68/10	220/35	220/35	220/35			
C5	100/16	100/10	100/10	150/35	150/35	150/35			
C6	100/16	100/10	100/10	120/35	120/35	120/35			
C7	68/10	100/10	68/10	150/35	150/35	150/35			
C8	100/16	100/10	100/10	330/35	330/35	330/35			
C9	100/16	100/16	100/16	330/35	330/35	330/35			
C10	100/16	100/16	68/16	220/35	220/35	220/35			
C11	100/16	100/16	68/16	150/35	150/35	150/35			
C12	100/16	100/16	68/16	120/35	120/35	120/35			
C13	100/16	100/16	100/16	120/35	120/35	120/35			
C14	100/16	100/16	100/16	220/35	220/35	220/35			
C15	47/20	68/20	47/20	220/35	220/35	220/35			
C16	47/20	68/20	47/20	150/35	150/35	150/35			
C17	47/20	68/20	47/20	120/35	120/35	120/35			
C18	68/25	(2×) 33/25	47/25 <sup>(1)</sup>	220/35	220/35	220/35			
C19	33/25	33/25	33/25 (1)	150/35	150/35	150/35			
C20	33/25	33/25	33/25 <sup>(1)</sup>	120/35	120/35	120/35			
C21	33/35	(2×) 22/25	(2)	150/35	150/35	150/35			
C22	33/35	22/35	(2)	120/35	120/35	120/35			
C23	(2)	(2)	(2)	220/50	100/50	120/50			
C24	(2)	(2)	(2)	150/50	100/50	120/50			
C25	(2)	(2)	(2)	150/50	82/50	82/50			

<sup>(1)</sup> The SC series of Os-Con capacitors (others are SA series)

#### 9.2.2.2.4 Catch Diode Selection (D1)

1. In normal operation, the average current of the catch diode is the load current times the catch diode duty cycle, 1-D (D is the switch duty cycle, which is approximately V<sub>OUT</sub>/V<sub>IN</sub>). The largest value of the catch diode average current occurs at the maximum input voltage (minimum D). For normal operation, the catch diode current rating must be at least 1.3 times greater than its maximum average current. However, if the power supply design must withstand a continuous output short, the diode must have a current rating greater than the maximum current limit of the LM2671. The most stressful condition for this diode is a shorted output condition.

Refer to the table shown in Table 4. Schottky diodes provide the best performance, and in this example a 1-A, 40-V Schottky diode would be a good choice. If the circuit must withstand a continuous shorted output, a higher current (at least 1.2 A) Schottky diode is recommended.

- 2. The reverse voltage rating of the diode must be at least 1.25 times the maximum input voltage.
- 3. Because of their fast switching speed and low forward voltage drop, Schottky diodes provide the best performance and efficiency. The Schottky diode must be placed close to the LM2671 using short leads and short printed-circuit traces.

<sup>(2)</sup> The voltage ratings of the surface mount tantalum chip and Os-Con capacitors are too low to work at these voltages.



#### 9.2.2.2.5 Input Capacitor (C<sub>IN</sub>)

A low ESR aluminum or tantalum bypass capacitor is required between the input pin and ground to prevent large voltage transients from appearing at the input. This capacitor must be placed close to the IC using short leads. In addition, the RMS current rating of the input capacitor must be selected to be at least ½ the DC load current. The capacitor manufacturer data sheet must be checked to assure that this current rating is not exceeded. The curves shown in Figure 16 show typical RMS current ratings for several different aluminum electrolytic capacitor values. A parallel connection of two or more capacitors may be required to increase the total minimum RMS current rating to suit the application requirements.

For an aluminum electrolytic capacitor, the voltage rating must be at least 1.25 times the maximum input voltage. Caution must be exercised if solid tantalum capacitors are used. The tantalum capacitor voltage rating must be twice the maximum input voltage. The Table 10 and Table 11 show the recommended application voltage for AVX TPS and Sprague 594D tantalum capacitors. TI also recommends that they be surge current tested by the manufacturer. The TPS series available from AVX, and the 593D and 594D series from Sprague are all surge current tested. Another approach to minimize the surge current stresses on the input capacitor is to add a small inductor in series with the input supply line.

 RECOMMENDED APPLICATION VOLTAGE
 VOLTAGE RATING

 85°C RATING
 85°C RATING

 3.3
 6.3

 5
 10

 10
 20

 12
 25

 15
 35

Table 10. AVX TPS

Table 11. Sprague 594D

RECOMMENDED APPLICATION VOLTAGE	VOLTAGE RATING
85°C R	ATING
2.5	4
3.3	6.3
5	10
8	16
12	20
18	25
24	35
29	50

Use caution when using ceramic capacitors for input bypassing, because it may cause severe ringing at the  $V_{IN}$  pin.

The important parameters for the input capacitor are the input voltage rating and the RMS current rating. With a maximum input voltage of 28 V, an aluminum electrolytic capacitor with a voltage rating of at least  $35 \text{ V} (1.25 \times \text{V}_{\text{IN}})$  is required.

The RMS current rating requirement for the input capacitor in a buck regulator is approximately ½ the DC load current. In this example, with a 500-mA load, a capacitor with a RMS current rating of at least 250 mA is required. The curves shown in Figure 22 can be used to select an appropriate input capacitor. From the curves, locate the 35-V line and note which capacitor values have RMS current ratings greater than 250 mA.

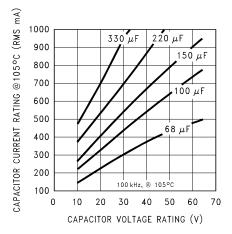


Figure 22. RMS Current Ratings for Low ESR Electrolytic Capacitors (Typical)

For a through-hole design, a 68-μF, 35-V electrolytic capacitor (Panasonic HFQ series, Nichicon PL, Sanyo MV-GX series or equivalent) would be adequate. Other types or other manufacturers' capacitors can be used provided the RMS ripple current ratings are adequate. Additionally, for a complete surface mount design, electrolytic capacitors such as the Sanyo CV-C or CV-BS and the Nichicon WF or UR and the NIC Components NACZ series could be considered.

For surface mount designs, solid tantalum capacitors can be used, but caution must be exercised with regard to the capacitor surge current rating and voltage rating. In this example, checking the Sprague 594D series data sheet, a Sprague 594D 15- $\mu$ F, 50-V capacitor is adequate.

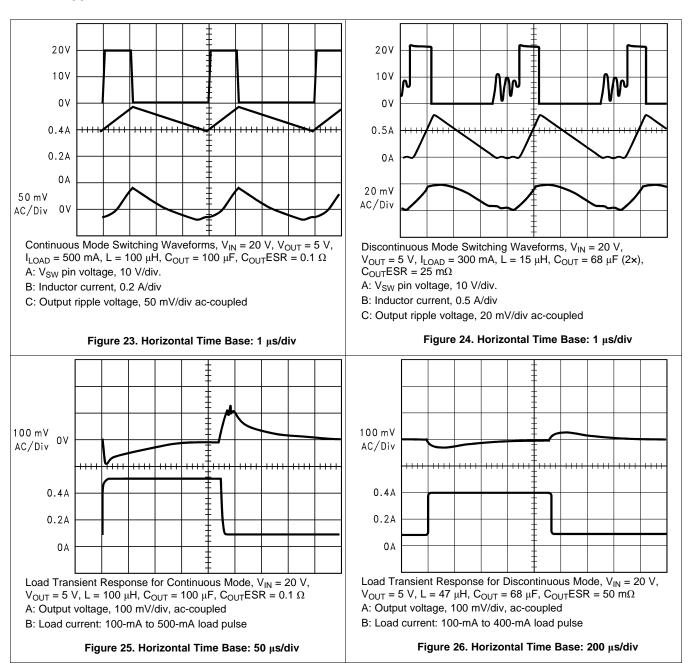
#### 9.2.2.2.6 Boost Capacitor (C<sub>R</sub>)

This capacitor develops the necessary voltage to turn the switch gate on fully. All applications must use a  $0.01-\mu F$ , 50-V ceramic capacitor. For this application, and all applications, use a  $0.01-\mu F$ , 50-V ceramic capacitor.

If the soft-start and frequency synchronization features are desired, look at steps 6 and 7 in *Detailed Design Procedure*.

# TEXAS INSTRUMENTS

### 9.2.2.3 Application Curves



# 10 Power Supply Recommendations

The LM2671 is designed to operate from an input voltage supply up to 40 V. This input supply must be well regulated and able to withstand maximum input current and maintain a stable voltage.



# 11 Layout

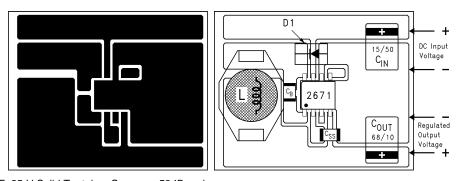
# 11.1 Layout Guidelines

Layout is very important in switching regulator designs. Rapidly switching currents associated with wiring inductance can generate voltage transients which can cause problems. For minimal inductance and ground loops, the wires indicated by heavy lines (in Figure 15 and Figure 21) must be wide printed-circuit traces and must be kept as short as possible. For best results, external components must be placed as close to the switcher IC as possible using ground plane construction or single point grounding.

If open core inductors are used, take special care as to the location and positioning of this type of inductor. Allowing the inductor flux to intersect sensitive feedback, IC ground path, and C<sub>OUT</sub> wiring can cause problems.

When using the adjustable version, take special care as to the location of the feedback resistors and the associated wiring. Physically place both resistors near the IC, and route the wiring away from the inductor, especially an open core type of inductor.

# 11.2 Layout Examples



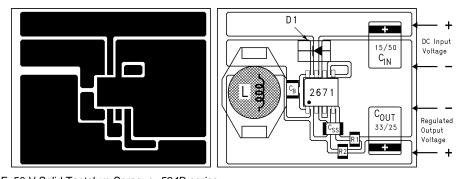
 $C_{IN}$  = 15- $\mu$ F, 25-V Solid Tantalum Sprague, 594D series  $C_{OLIT}$  = 68- $\mu$ F, 10-V Solid Tantalum Sprague, 594D series

D1 = 1-A, 40-V Schottky Rectifier, surface mount

L1 = 47-uH, L13 Coilcraft DO3308

 $C_B = 0.01-\mu F$ , 50-V ceramic

Figure 27. Typical Surface Mount PCB Layout, Fixed Output (4x Size)



 $C_{IN}$  = 15  $\mu$ F, 50 V Solid Tantalum Sprague, *594D series*  $C_{OUT}$  = 33  $\mu$ F, 25 V Solid Tantalum Sprague, *594D series* 

D1 = 1-A, 40-V Schottky Rectifier, surface mount

L1 = 100- $\mu$ H, L20 Coilcraft DO3316

 $C_B = 0.01 - \mu F$ , 50-V ceramic

 $R1 = 1 k\Omega, 1\%$ 

R2 = Use formula in *Detailed Design Procedure* 

Figure 28. Typical Surface Mount PCB Layout, Adjustable Output (4x Size)



# 12 Device and Documentation Support

# 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following:

- AN-1187 Leadless Leadfram Package (LLP)
- LM2670 SIMPLE SWITCHER® High Efficiency 3A Step-Down Voltage Regulator with Sync

# 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

# 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.4 Trademarks

E2E is a trademark of Texas Instruments.

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All other trademarks are the property of their respective owners.

#### 12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

#### 13.1 DAP (WSON Package)

The die attach pad (DAP) can and must be connected to the PCB Ground plane. For CAD and assembly guidelines refer to AN-1187 Leadless Leadfram Package (LLP).

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# **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
LM2671LD-ADJ/NOPB	Active	Production	WSON (NHN)   16	1000   SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	S0008B
LM2671LD-ADJ/NOPB.B	Active	Production	WSON (NHN)   16	1000   SMALL T&R	Yes	SN	Level-3-260C-168 HR	-40 to 125	S0008B
LM2671M-12/NOPB	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M-12
LM2671M-12/NOPB.B	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M-12
LM2671M-3.3/NOPB	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M3.3
LM2671M-3.3/NOPB.B	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M3.3
LM2671M-5.0/NOPB	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M5.0
LM2671M-5.0/NOPB.B	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M5.0
LM2671M-ADJ/NOPB	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 MADJ
LM2671M-ADJ/NOPB.B	Active	Production	SOIC (D)   8	95   TUBE	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 MADJ
LM2671MX-12/NOPB	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M-12
LM2671MX-12/NOPB.B	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M-12
LM2671MX-3.3/NOPB	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M3.3
LM2671MX-3.3/NOPB.B	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M3.3
LM2671MX-5.0/NOPB	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M5.0
LM2671MX-5.0/NOPB.B	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 M5.0
LM2671MX-ADJ/NOPB	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 MADJ





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Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	(3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
LM2671MX-ADJ/NOPB.B	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	2671 MADJ
LM2671N-12/NOPB	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-12
LM2671N-12/NOPB.B	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-12
LM2671N-3.3/NOPB	Active	Production	PDIP (P)   8	40   TUBE	Yes	Call TI   Nipdau	Level-1-NA-UNLIM	-40 to 125	LM2671 N-3.3
LM2671N-3.3/NOPB.B	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-3.3
LM2671N-5.0/NOPB	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-5.0
LM2671N-5.0/NOPB.B	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-5.0
LM2671N-ADJ/NOPB	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-ADJ
LM2671N-ADJ/NOPB.B	Active	Production	PDIP (P)   8	40   TUBE	Yes	NIPDAU	Level-1-NA-UNLIM	-40 to 125	LM2671 N-ADJ

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



# **PACKAGE OPTION ADDENDUM**

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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# TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM2671LD-ADJ/NOPB	WSON	NHN	16	1000	177.8	12.4	5.3	5.3	1.3	8.0	12.0	Q1
LM2671MX-12/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2671MX-3.3/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2671MX-5.0/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LM2671MX-ADJ/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1



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#### \*All dimensions are nominal

7 til dillionsions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM2671LD-ADJ/NOPB	WSON	NHN	16	1000	208.0	191.0	35.0
LM2671MX-12/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2671MX-3.3/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2671MX-5.0/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LM2671MX-ADJ/NOPB	SOIC	D	8	2500	367.0	367.0	35.0



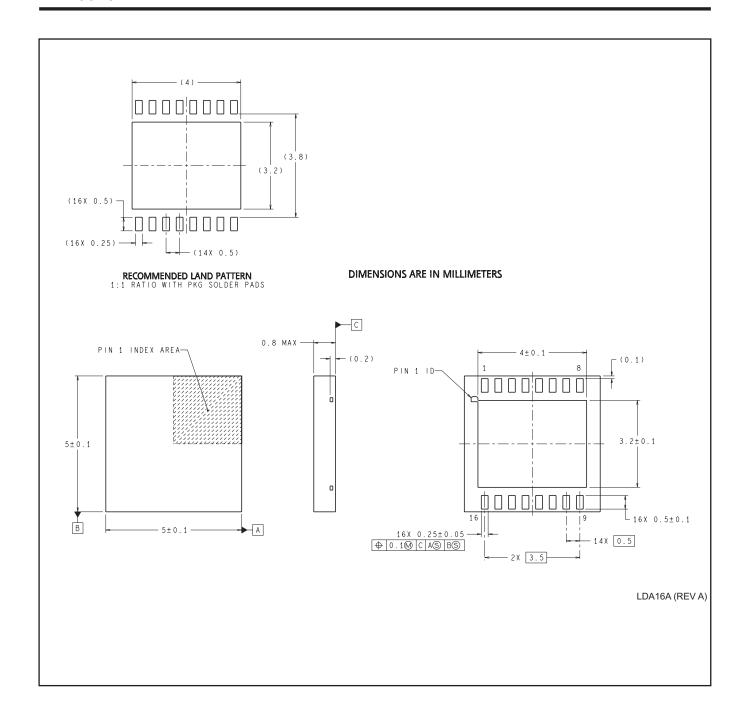
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# **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LM2671M-12/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2671M-12/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM2671M-3.3/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2671M-3.3/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM2671M-5.0/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2671M-5.0/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM2671M-ADJ/NOPB	D	SOIC	8	95	495	8	4064	3.05
LM2671M-ADJ/NOPB.B	D	SOIC	8	95	495	8	4064	3.05
LM2671N-12/NOPB	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-12/NOPB.B	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-3.3/NOPB	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-3.3/NOPB.B	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-5.0/NOPB	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-5.0/NOPB.B	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-ADJ/NOPB	Р	PDIP	8	40	502	14	11938	4.32
LM2671N-ADJ/NOPB.B	Р	PDIP	8	40	502	14	11938	4.32





SMALL OUTLINE INTEGRATED CIRCUIT



# NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# P (R-PDIP-T8)

# PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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